

# Chapt8Fig15.m

## Screened vs Unscreened Coulomb Scattering

### Demonstrating the Effect of Thomas-Fermi Screening

Semiconductor Physics Documentation

#### Abstract

This document analyzes Chapt8Fig15.m, which compares the angular distribution of scattering rates with and without Thomas-Fermi screening. This comparison vividly demonstrates how screening regularizes the divergent bare Coulomb scattering at small angles.

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# 1 Theoretical Foundation

## 1.1 Bare Coulomb Scattering

**Theorem 1** (Rutherford Scattering Rate). *For bare Coulomb scattering (no screening):*

$$\frac{d(1/\tau)}{d\theta} = \frac{2\pi m^*}{\hbar^3 k^3} n_i \left( \frac{e^2}{4\pi\epsilon_0\epsilon_r} \right)^2 \frac{\sin\theta}{q^4} \quad (1)$$

where  $q = 2k \sin(\theta/2)$ .

**Corollary 1** (Small-Angle Divergence). *As  $\theta \rightarrow 0$ :*

$$\frac{d(1/\tau)}{d\theta} \propto \frac{\theta}{(k\theta)^4} = \frac{1}{k^4 \theta^3} \rightarrow \infty \quad (2)$$

This divergence is unphysical and leads to an infinite total scattering rate.

## 1.2 Screened Coulomb Scattering

**Theorem 2** (Thomas-Fermi Screened Rate). *With Thomas-Fermi screening:*

$$\frac{d(1/\tau)}{d\theta} = \frac{2\pi m^*}{\hbar^3 k^3} n_i \left( \frac{e^2}{4\pi\epsilon_0} \right)^2 \frac{\sin\theta}{\epsilon_{TF}^2(q) \cdot q^4} \quad (3)$$

where:

$$\epsilon_{TF}(q) = \epsilon_r \left( 1 + \frac{q_{TF}^2}{q^2} \right) \quad (4)$$

**Corollary 2** (Regularization). *As  $\theta \rightarrow 0$  with screening:*

$$\frac{d(1/\tau)}{d\theta} \propto \frac{\theta}{(q_{TF}^2)^2} = \text{finite} \quad (5)$$

The screening wavevector  $q_{TF}$  provides a natural cutoff.

## 1.3 Physical Origin of Screening

**Definition 1** (Debye-Hückel/Thomas-Fermi Picture). *Mobile electrons redistribute around a charged impurity:*

$$\delta n(r) \propto e^{-q_{TF}r} \quad (6)$$

This creates a screening cloud that reduces the effective range of the Coulomb potential.

The screened potential in real space:

$$V(r) = \frac{Ze^2}{4\pi\epsilon_0\epsilon_r r} e^{-q_{TF}r} \quad (7)$$

This Yukawa-type potential has a finite range  $\sim 1/q_{TF}$ .

# 2 Line-by-Line Code Analysis

## 2.1 Initialization

```

1 clear; clf;
2 n=1e18;
3 n=n*1e6;
```

$$n = 10^{18} \text{ cm}^{-3} = 10^{24} \text{ m}^{-3} \quad (8)$$

High carrier density for strong screening.

## 2.2 Physical Constants

```

1 m0=9.109382e-31;
2 echarge=1.6021764e-19;
3 epsilon0=8.8541878e-12;
4 hbar=1.05457159e-34;
5 hbar3=hbar^3;

```

*Note: Variable name is “echarge” (typo for “echarge”).*

```

1 m=0.07*m0;
2 epsilonr0=13.2;
3 epsilon=epsilon0*epsilonr0;

```

$$m^* = 0.07m_0, \quad \varepsilon = 13.2\varepsilon_0 \quad (9)$$

*GaAs parameters.*

## 2.3 Fermi Wavevector

```

1 kF=(3*(pi^2)*n)^(1/3)

```

$$k_F = (3\pi^2 \times 10^{24})^{1/3} \approx 3.09 \times 10^8 \text{ m}^{-1} \quad (10)$$

*Fermi wavevector for degenerate electron gas.*

## 2.4 Energy Loop

```

1 E=-0.1*echarge;
2 for j=1:1:2
3 E=E+0.2*echarge
4 k=sqrt(2*m*E)/hbar;
5 k3=k^3;

```

$$E \in \{0.1, 0.3\} \text{ eV} \quad (11)$$

*Two electron energies (note: E is in Joules since multiplied by “echarge”).*

## 2.5 RPA Constants (Unused in Final Calculation)

```

1 rs0=((3/(4*pi*n))^(1/3))*(m*(echarge^2)/(4*pi*epsilon0*(hbar^2)));
2 xi=((32*(pi^2)/9)^(1/3))/(pi^2);

```

*These RPA constants are calculated but not used in the plotted rates.*

## 2.6 Thomas-Fermi Wavevector

```

1 qTF=sqrt(kF*m*echarge^2/(epsilon*(pi^2)*(hbar^2)));

```

$$q_{\text{TF}} = \sqrt{\frac{k_F m^* e^2}{\varepsilon \pi^2 \hbar^2}} \quad (12)$$

*Thomas-Fermi screening wavevector.*

## 2.7 Angular Grid

```

1 theta=[pi/180:pi/180:pi];
2     q=2*k*sin(theta/2);
3 eta=sin(theta/2);
4 deta=pi*cos(theta/2)./2/180;
5 eta3=eta.^3;

```

$$\theta \in [1, 180], \quad q = 2k \sin(\theta/2) \quad (13)$$

*Standard angular discretization.*

## 2.8 Thomas-Fermi Dielectric Function

```

1 TFepsilon=epsilon*(1+qTF.^2./q.^2);

```

$$\varepsilon_{\text{TF}}(q) = \varepsilon \left( 1 + \frac{q_{\text{TF}}^2}{q^2} \right) \quad (14)$$

*Screened dielectric function.*

## 2.9 Unscreened (Bare Coulomb) Rate

```

1 NoScreenRate=2*pi*m/hbar3/k3*n*(echarge.^2/4/pi)^2.*deta./epsilon.^2./
    eta3;

```

$$\left( \frac{1}{\tau} \right)_{\text{bare}} = \frac{2\pi m^*}{\hbar^3 k^3} n \left( \frac{e^2}{4\pi} \right)^2 \frac{d\eta}{\varepsilon^2 \eta^3} \quad (15)$$

*Bare Coulomb scattering rate (no screening, only background dielectric constant).*

## 2.10 Thomas-Fermi Screened Rate

```

1 TFrater=2*pi*m/hbar3/k3*n*(echarge.^2/4/pi)^2.*deta./TFepsilon.^2./
    eta3;

```

$$\left( \frac{1}{\tau} \right)_{\text{TF}} = \frac{2\pi m^*}{\hbar^3 k^3} n \left( \frac{e^2}{4\pi} \right)^2 \frac{d\eta}{\varepsilon_{\text{TF}}^2 \eta^3} \quad (16)$$

*Thomas-Fermi screened scattering rate.*

## 2.11 Plotting Both Curves

```

1 plot(theta*180/pi, TFrater, 'r');
2 axis([0 180 0 0.3e12]);
3 ...
4 plot(theta*180/pi, NoScreenRate, 'b');

```

*Red: Thomas-Fermi screened; Blue: Bare Coulomb (unscreened).*

## 3 Physical Interpretation

### 3.1 Comparison of Curves

- **Blue curve (unscreened):** Diverges at small angles
- **Red curve (TF screened):** Finite at all angles
- At large angles ( $\theta \gtrsim 90^\circ$ ): Both curves similar
- At small angles ( $\theta \lesssim 30^\circ$ ): Dramatic difference

### 3.2 Crossover Angle

The screening becomes important when  $q \sim q_{\text{TF}}$ :

$$2k \sin(\theta_c/2) \approx q_{\text{TF}} \quad (17)$$

$$\theta_c \approx 2 \arcsin\left(\frac{q_{\text{TF}}}{2k}\right) \quad (18)$$

For small angles:

$$\theta_c \approx \frac{q_{\text{TF}}}{k} \quad (19)$$

### 3.3 Total Scattering Rate

Without screening:

$$\frac{1}{\tau_{\text{bare}}} = \int_0^\pi \frac{d(1/\tau)}{d\theta} d\theta = \infty \quad (20)$$

With Thomas-Fermi screening:

$$\frac{1}{\tau_{\text{TF}}} = \int_0^\pi \frac{d(1/\tau)}{d\theta} d\theta = \text{finite} \quad (21)$$

### 3.4 Practical Implications

- Bare Coulomb formula (Rutherford) cannot be used for transport calculations
- Screening is essential for finite mobility in doped semiconductors
- Higher doping  $\Rightarrow$  stronger screening  $\Rightarrow$  can partially compensate for more scatterers

## 4 Summary

This code provides a direct visual comparison between screened and unscreened Coulomb scattering, demonstrating:

1. The bare Coulomb potential leads to divergent scattering at small angles
2. Thomas-Fermi screening regularizes this divergence
3. The crossover occurs at angle  $\theta_c \sim q_{\text{TF}}/k$
4. At large angles, screening effects are minimal

This is a fundamental result in semiconductor transport theory, explaining why heavily doped semiconductors can still have finite (though reduced) mobility.